- Center V<sub>CC</sub> and GND Configuration
   Provides Minimum Lead Inductance in High
   Current Switching Applications
- 3-State Buffer-Type Outputs Drive Bus-Lines Directly
- Bus-Structured Pinout
- Provide Extra Bus Driving Latches
   Necessary for Wider Address/Data Paths or
   Buses With Parity
- Buffered Control Inputs to Reduce DC Loading
- Power-Up High Impedance
- Package Options Include Plastic DIPs. Use the 'AS843 for Plastic and Ceramic Chip Carriers and "Small Outline" Package Options
- Dependable Texas Instruments Quality and Reliability

#### description

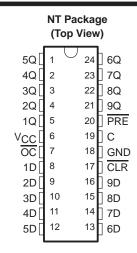
This 9-bit latch device features three-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. It is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

The nine latches are transparent D-type and have noninverting data (D) inputs.

A buffered output control ( $\overline{OC}$ ) input can be used to place the nine outputs in either a normal logic state (high or low levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive the bus lines in a bus-organized system without need for interface or pullup components.

The output control  $(\overline{OC})$  does not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are off.

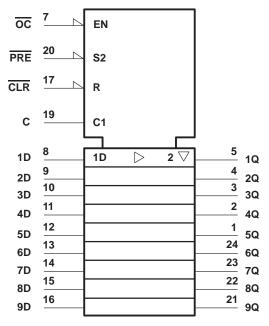
The SN74AS1843 is characterized for operation from 0°C to 70°C.



#### **FUNCTION TABLE**

INPUTS				OUTPUT	
PRE	CLR	OC	С	D	Q
L	Х	L	Х	Х	Н
Н	L	L	X	X	L
Н	Н	L	Н	L	L
Н	Н	L	Н	Н	Н
Н	Н	L	L	X	QO
X	X	Н	Χ	Χ	Z

### logic symbol †

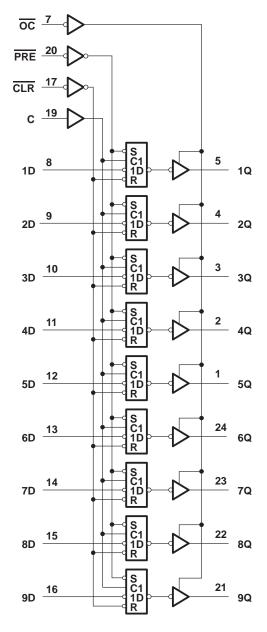


† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12,



1

#### logic diagram (positive logic)



## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V <sub>CC</sub> (see Note 1)	7 V
Input voltage	7 V
Voltage applied to a disabled 3-state output	5.5 V
Operating free-air temperature range	0°C to 70°C
Storage temperature range	- 65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the "Recommended Operating Conditions" section of this specification is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. NOTE 1: All voltage values are with respect to GND.



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### recommended operating conditions

			MIN	NOM	MAX	UNIT
Vcc	Supply voltage		4.5	5	5.5	V
VIH	High-level input voltage		2			V
V <sub>IL</sub>	Low-level input voltage				0.8	V
IOH	High-level output current				-24	mA
loL	Low-level output current				48	mA
	Pulse duration, enable C high	CLR or PRE low	4			
t <sub>W</sub>	Fulse duration, enable Chigh	C high	48 4 4 2.5	ns		
t <sub>su</sub>	Setup time, data before enable C $\downarrow$		2.5			ns
th	Hold time, data after enable C $\downarrow$		2.5			ns
t <sub>r</sub> Recovery time	Pacayary time	PRE	15			
	Necovery unie	CLR	14			ns
TA	Operating free-air temperature		0		70	°C

# electrical characteristics over full ranges of recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP <sup>†</sup>	MAX	UNIT
VIK	V <sub>CC</sub> = 4.5 V,	$I_{I} = -18 \text{ mA}$			-1.2	V
Vон	V <sub>CC</sub> = 4.5 V,	$I_{OH} = -2 \text{ mA}$	V <sub>CC</sub> -2			
	V <sub>CC</sub> = 4.5 V,	I <sub>OH</sub> = – 15 mA	2.4	3.2		V
	V <sub>CC</sub> = 4.5 V,	$I_{OH} = -24 \text{ mA}$	2			
. ,	V <sub>CC</sub> = 4.5 V,	$I_{OL} = 32 \text{ mA}$				V
VOL	V <sub>CC</sub> = 4.5 V,	I <sub>OL</sub> = 48 mA		0.35	0.5	
lozh	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.7 V			50	μА
lozL	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 0.4 V			-50	μА
l <sub>l</sub>	$V_{CC} = 5.5 V$ ,	V <sub>I</sub> = 7 V			0.1	mA
lіН	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 2.7 V			20	μА
I <sub>IL</sub>	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 0.4 V			05	mA
I <sub>O</sub> ‡	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.25 V	-30		-112	mA
<sup>I</sup> cc		Output high		37	7 62	
	$V_{CC} = 5.5 V,$	Output low		56	92	mA
		Outputs disabled		56	92	

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

<sup>&</sup>lt;sup>‡</sup> The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, los.

## SN74AS1843 9-BIT BUS INTERFACE D-TYPE LATCHES WITH 3-STATE OUTPUTS

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# switching characteristics over recommended ranges of supply voltage and free-air temperature (see Note 2)

PARAMETER	FROM (INPUT)	ТО (ОИТРИТ)	$\begin{tabular}{ll} $V_{CC} = 4.5 \ V$ to 5.5 \ V$, \\ $C_L = 50 \ pF$, \\ $R_1 = 500 \ \Omega$, \\ $R_2 = 500 \ \Omega$, \\ $T_A = MIN \ to \ MAX$ \end{tabular}$		UNIT
			MIN	MAX	
<sup>t</sup> PLH	D		1	6.5	ns
t <sub>PHL</sub>		Q	1	9	
t <sub>PLH</sub>	С		2	12	
<sup>t</sup> PHL		Q	2	12	ns
t <sub>PLH</sub>	PRE	Q	2	10	ns
<sup>t</sup> PHL	CLR	Q	2	13	ns
<sup>t</sup> PZH			2	10.5	
tPZL	<del>oc</del>	Q	2	13.5	ns
<sup>t</sup> PHZ			1	8	
t <sub>PLZ</sub>	<del>OC</del>	Q	1	8	ns

NOTE 2: Load circuit and voltage waveforms are shown in Section 1 of the ALS/AS Logic Data Book, 1986.

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